



Data Sheet

## A COMPLEMENTARY SILICON POWER TRANSISTORS 250 V, 200 W

Manufacturers ON Semiconductor, LLC

Package/Case TO-3PL

Transistors Product Type

**RoHS** Pb-free

Lifecycle



Images are for reference only

Please submit RFQ for MJL21195G or Email to us: sales@ovaga.com We will contact you in 12 hours.



## **General Description**

The MJL21195 and MJL21196 Bipolar Complementary Audio Power Transistors utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

**Application Features** 

Total Harmonic Distortion Characterized

High DC Current Gain - = 8 Adc

**Excellent Gain Linearity** 

High SOA: 2.25 A, 80 V, 1 Second

**ONSEMI** 



## **Related Products**



MJE172

ON Semiconductor, LLC





MJD42CT4G

ON Semiconductor, LLC SOT25



**MJ802G** 

ON Semiconductor, LLC TO-204-2



**MJH6287** 

ON Semiconductor, LLC TO-247



**MJE350G** 

ON Semiconductor, LLC TO-126



MJD44H11-1G

ON Semiconductor, LLC TO-251



**MJ4502G** 

ON Semiconductor, LLC TO-204-2 (TO-3)



MJE5852

ON Semiconductor, LLC TO-220